RF Components

CB Series

Double Balanced Mixers Pin-Terminal Type

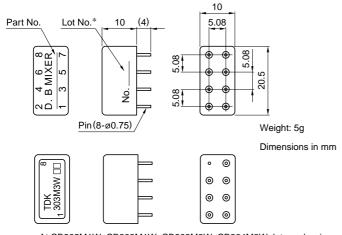
FEATURES

- Compact suitable for high-density mounting configurations.
- Wideband characteristics.
- · No induction noise (EMC).
- Reliable performance over an extended service life.

APPLICATIONS

Radio equipment, broadcast equipment, studio equipment, measuring devices.

8-PIN TYPE **SHAPES AND DIMENSIONS**



*At CB302M1W, CB303M1W, CB303M3W, CB304M3W, lot number is printed on upper side.

CIRCUIT DIAGRAMS Fig.A Fig.B Fig.C

PIN CONNECTIONS

I III OOIIIILOI	10110							
No.	1	2	3	4	5	6	7	8
LO	1	1	1	8	8	8	8	8
RF	8	5, 6	8	1	1	3, 4	1	1
IF	5, 6	8	5, 6	3	3, 4	1	3, 4	3
Ground	2, 3, 4, 7	2, 3, 4, 7	2, 3, 4, 7	2, 5, 6, 7	2, 5, 6, 7	2, 5, 6, 7	2, 5, 6, 7	2, 5, 6, 7
Case ground	7	2, 3, 4, 7	2, 3, 4, 7	2, 5, 6, 7	2	2, 5, 6, 7	2, 5, 6, 7	2, 5, 6, 7
NC				4				4

ELECTRICAL CHARACTERISTICS

Part No.	Frequency RF(MHz) LO(MHz)	range IF(MHz)	Conversion loss (dB)max.	Isolation (dB)min. LO-RF	LO-IF	RF input for 1dB compression level (dBm)typ.	3rd order intercept point (dBm)typ.	Max. input power (mW)	LO power (dBm)	Pin connections No.	Circuit Fig.
Low level CE	33M Serie	S									
CB312M1*	0.3 to 250	DC to 250	7.5	25	25	-1	+17.5	50	+7	1	С
CB302M1W	0.3 to 400	DC to 300	8	25	25	0	+15	200	+7	1	Α
CB303M1W	1 to 500	DC to 500	8	30	23	0	+15	200	+7	1	Α
CB304M1	1 to 1000	1 to 500	8	25	20	+1	+9	50	+7	2	Α
CB313M1	1 to 500	DC to 500	8	25	25	-1	+15	50	+7	1	С
CB314M1A	1 to 1000	0.5 to 400	8	20	20	-1	+10	50	+7	2	С
CB324M1	5 to 1000	DC to 1000	9	25	20	-1	+10	50	+7	3	С
CB334M1	5 to 1000	DC to 1000	9	25	20	0	+12.5	50	+7	3	Α
CB346M1A	1 to 2200	0.5 to 500	10	25	20	+1	+17.5	50	+7	4	В

^{*} M1, M1A, M1W specifications apply when operated at +7dBm available LO power, with 50Ω source.

[•] Temprature range: -20 to +80°C

RF Components

CB Series

Double Balanced Mixers Pin-Terminal Type

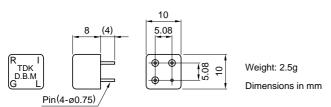
8-PIN TYPE ELECTRICAL CHARACTERISTICS

Part No.	Frequency r RF(MHz) LO(MHz)	range IF(MHz)	Conversion loss (dB)max.	Isolation (dB)min. LO-RF	LO-IF	RF input for 1dB compression level (dBm)typ.	3rd order intercept point (dBm)typ.	Max. input power (mW)	LO power (dBm)	Pin connections No.	Circuit Fig.
High level Cl	33M Serie	S									
CB302M2	0.1 to 200	DC to 200	7.5	25	25	+8	+20	50	+17	1	С
CB303M2	1 to 500	DC to 500	8	25	25	+8	+22.5	50	+17	1	С
CB303M3W	1 to 600	DC to 600	8.5	25	25	+9	+15	200	+17	1	Α
CB304M3W	1 to 700	DC to 700	9	25	20	+7	+15	200	+17	3	Α
CB304M2	5 to 950	1 to 600	8	25	20	+5	+12.5	50	+17	2	С
Low level CE	33M_B Se	ries for Low co	st								
CB312M1B	0.5 to 250	DC to 250	7	30	30	0	+15	50	+7	5	Α
CB313M1B	5 to 500	DC to 500	8	30	25	0	+15	50	+7	5	Α
CB314M1B	0.1 to 1000	0.5 to 500	8	25	30	0	+10	50	+7	6	Α
CB324M1B	0.5 to 1000	DC to 1000	10	30	25	+2	+13	50	+7	7	Α
CB346M1B	1 to 2200	0.5 to 500	10	20	20	+1	+17.5	50	+7	4	В
High level Cl	33M_B Se	ries for Low co	ost								
CB302M2B	0.5 to 250	DC to 250	7	30	30	+9	+18	50	+17	5	Α
CB303M2B	5 to 500	DC to 500	8	30	25	+8	+20	50	+17	5	Α
CB304M2B	0.1 to 1000	0.5 to 700	8	25	25	+7	+17	50	+17	6	Α
CB324M2B	0.5 to 1000	DC to 1000	10	25	25	+8	+20	50	+17	7	Α

^{*} M1B specifications apply when operated at +7dBm available LO power, with 50Ω source. M2, M3W, M2B specifications apply when operated at +17dBm available LO power, with 50Ω source

4-PIN TYPE

SHAPES AND DIMENSIONS



PIN CONNECTIONS

LO	L
RF	R
IF	I
Ground	G





CIRCUIT DIAGRAMS

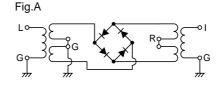


Fig.B

ELECTRICAL CHARACTERISTICS

	7.L O. 17.117.1	J. L. (10 1100								
Part No.	Frequency range		Conversion	Isolation		RF input for 1dB	3rd order	May input	10	
	RF(MHz) LO(MHz)	IF(MHz)	Conversion loss (dB)max.	(dB)min. LO-RF	LO-IF	compression level (dBm)typ.	intercept point (dBm)typ.	Max. input power (mW)	LO power (dBm)	Circuit Fig.
Low level C	B4M1 Serie	S								
CB413M1*	0.1 to 500	DC to 500	8.5	20	20	0	+10	50	+7	В
CB414M1	0.1 to 1000	0.5 to 500	9	18	20	0	+10	50	+7	Α
CB424M1	0.1 to 1000	DC to 1000	11	20	18	0	+13	50	+7	В
High level C	B4_ M2 Serie	es								
CB413M2	0.1 to 500	DC to 500	8.5	20	20	+7	+14	50	+17	В
CB414M2	0.1 to 1000	0.5 to 700	9	18	20	+6	+14	50	+17	Α
CB424M2	0.1 to 1000	DC to 1000	11	20	18	+9	+16	50	+17	В

^{*} M1 specifications apply when operated at +7dBm available LO power, with 50Ω source. M2 specifications apply when operated at +17dBm available LO power, with 50Ω source.

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[•] Temprature range: -20 to +80°C

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